

RELIABILITY REPORT
FOR

DS2703 Rev A2-6"

Dallas Semiconductor

4401 South Beltwood Parkway
Dallas, TX 75244-3292

Prepared by:

Ken Wendel

Ken Wendel
Reliability Engineering Manager
Dallas Semiconductor
4401 South Beltwood Pkwy.
Dallas, TX 75244-3292
Email : ken.wendel@dalsemi.com
ph: 972-371-3726
fax: 972-371-6016
mbl: 214-435-6610

Conclusion:

The following Reliability Test successfully meets the quality and reliability standards set forth by this special Temperature Cycle Evaluation:

DS2703 Rev A2-6"

Device Description:

A description of the device used in this qualification can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature
tu = Time at use temperature (e.g. 55°C)
ts = Time at stress temperature (e.g. 125°C)
k = Boltzmann's Constant (8.617 x 10⁻⁵ eV/°K)
Tu = Temperature at Use (°K)
Ts = Temperature at Stress (°K)
Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage
Vs = Stress Voltage (e.g. 7.0 volts)
Vu = Maximum Operating Voltage (e.g. 5.5 volts)
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$MTTF = 1/Fr$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process/assembly is:

FAILURE RATE: **MTTF (YRS): 5288** **FITS: 21.6**

The parameters used to calculate this failure rate are as follows:

Cf: 60% **Ea: 0.7** **B: 0** **Tu: 25 °C** **Vu: 5.5 Volts**

The reliability data follows. At the start of this data is the device information. This is a description of the device for this report. Following this is the assembly information. This section includes a description of the assembly vehicle used to generate this reliability data for both qualifications and monitors. The next section is the detailed reliability data for each stress found in the qualification / monitor. If there are additional assemblies used as part of this report, a description of each will follow which includes the respective reliability data for that assembly. The reliability data section includes the latest data available.

Device Information:

Device: DS2703
 Process: D35WN-3P3M,DPE2,NTC,DSD,PDESD,PDRES,Cap,ENPN,
 Passivation: TopMetal 2 Mask NRL: TEOS Ox/Nitride
 Die Size: 41 x 70
 Number of Transistors: 0
 Interconnect: Aluminum / 1% Silicon / 0.5% Copper
 Gate Oxide Thickness: 131 Å

Assembly Information:

Qualification Vehicle: DS2703
 Assembly Site: ATP (Amkor, PI)
 Pin Count: 8
 Package Type: uSOP
 Body Size: 3x0.85
 Mold Compound: Nitto MP8000C
 Lead Frame: Stamped Copper C7025
 Lead Finish: SnPb Plate
 Die Attach: 84-1 LMISR4 Epoxy Silverfilled Ablebond
 Bond Wire / Size: Au / 1.0 mil
 Theta JA: 221
 Theta JC: 39
 Flammability: UL 94-V0
 Moisture Sensitivity (JEDEC J-STD20A) Level 1
 Date Code Range: 0449 to 0449

ELECTRICAL CHARACTERIZATION

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QTY	FAILS	FA#
ESD SENSITIVITY	0449	EOS/ESD S5.1 HBM 500 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0449	EOS/ESD S5.1 HBM 1000 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0449	EOS/ESD S5.1 HBM 2000 VOLTS	1 PUL'S	3	0	

ESD SENSITIVITY	0449	EOS/ESD S5.1 HBM 4000 VOLTS	1	PUL'S	3	2	No FA
ESD SENSITIVITY	0449	EOS/ESD S5.1 HBM 8000 VOLTS	1	PUL'S	3	3	No FA
LATCH-UP	0449	JESD78, I-TEST 125C	2	DYS	6	0	
LATCH-UP	0449	JESD78, Vsupply TEST 125C	2	DYS	6	0	
Total:						5	

OPERATING LIFE

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QTY	FAILS	FA#
HIGH TEMP OP LIFE	0449	125C, 5.5 VOLTS	1000 HRS	45	0	
Total:						0

TEMPERATURE CYCLE

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QTY	FAILS	FA#
TEMP CYCLE	0449	-55C TO 125C	1000 CYS	77	0	
Total:						0

TEMPERATURE HUMIDITY BIAS

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QTY	FAILS	FA#
HAST	0449	130C, 85%R.H.,5.5V	96 HRS	77	0	
Total:						0

UNBIASED MOISTURE RESISTANCE

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QTY	FAILS	FA#
AUTOCLAVE	0449	121C, 2 ATM STEAM, UNBIASED	168 HRS	77	0	
Total:						0

W/E ENDURANCE AND DATA RET'N

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QTY	FAILS	FA#
WRITE CYCLE STRESS	0449	50 C, 5.5 VOLTS	1 KCYS	77	0	
STORAGE LIFE		150C	1000 HRS	77	0	
Total:						0

FAILURE RATE: MTTF (YRS): 5288

FITS: 21.6